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APPLICATION NO.	FILING DATE	FIRST NAMED INVENTOR	ATTORNEY DOCKET NO.	CONFIRMATION NO.
09/651,998	08/31/2000	Lingyi A Zheng	M4065.0315/P315	2931
24998	7590	04/26/2004	EXAMINER	
DICKSTEIN SHAPIRO MORIN & OSHINSKY LLP 2101 L STREET NW WASHINGTON, DC 20037-1526			TSAI, H JEY	
		ART UNIT	PAPER NUMBER	
		2812		

DATE MAILED: 04/26/2004

Please find below and/or attached an Office communication concerning this application or proceeding.

Office Action Summary	Application No.	Applicant(s)	
	09/651,998	ZHENG ET AL.	
	Examiner	Art Unit	
	H.Jey Tsai	2812	

-- The MAILING DATE of this communication appears on the cover sheet with the correspondence address --

Period for Reply

A SHORTENED STATUTORY PERIOD FOR REPLY IS SET TO EXPIRE 3 MONTH(S) FROM THE MAILING DATE OF THIS COMMUNICATION.

- Extensions of time may be available under the provisions of 37 CFR 1.136(a). In no event, however, may a reply be timely filed after SIX (6) MONTHS from the mailing date of this communication.
- If the period for reply specified above is less than thirty (30) days, a reply within the statutory minimum of thirty (30) days will be considered timely.
- If NO period for reply is specified above, the maximum statutory period will apply and will expire SIX (6) MONTHS from the mailing date of this communication.
- Failure to reply within the set or extended period for reply will, by statute, cause the application to become ABANDONED (35 U.S.C. § 133). Any reply received by the Office later than three months after the mailing date of this communication, even if timely filed, may reduce any earned patent term adjustment. See 37 CFR 1.704(b).

Status

1) Responsive to communication(s) filed on 26 January 2004.
 2a) This action is **FINAL**. 2b) This action is non-final.
 3) Since this application is in condition for allowance except for formal matters, prosecution as to the merits is closed in accordance with the practice under *Ex parte Quayle*, 1935 C.D. 11, 453 O.G. 213.

Disposition of Claims

4) Claim(s) 1-59 is/are pending in the application.
 4a) Of the above claim(s) _____ is/are withdrawn from consideration.
 5) Claim(s) _____ is/are allowed.
 6) Claim(s) 1-59 is/are rejected.
 7) Claim(s) _____ is/are objected to.
 8) Claim(s) _____ are subject to restriction and/or election requirement.

Application Papers

9) The specification is objected to by the Examiner.
 10) The drawing(s) filed on 31 August 2000 is/are: a) accepted or b) objected to by the Examiner.
 Applicant may not request that any objection to the drawing(s) be held in abeyance. See 37 CFR 1.85(a).
 Replacement drawing sheet(s) including the correction is required if the drawing(s) is objected to. See 37 CFR 1.121(d).
 11) The oath or declaration is objected to by the Examiner. Note the attached Office Action or form PTO-152.

Priority under 35 U.S.C. § 119

12) Acknowledgment is made of a claim for foreign priority under 35 U.S.C. § 119(a)-(d) or (f).
 a) All b) Some * c) None of:
 1. Certified copies of the priority documents have been received.
 2. Certified copies of the priority documents have been received in Application No. _____.
 3. Copies of the certified copies of the priority documents have been received in this National Stage application from the International Bureau (PCT Rule 17.2(a)).

* See the attached detailed Office action for a list of the certified copies not received.

Attachment(s)

1) <input checked="" type="checkbox"/> Notice of References Cited (PTO-892)	4) <input type="checkbox"/> Interview Summary (PTO-413)
2) <input type="checkbox"/> Notice of Draftsperson's Patent Drawing Review (PTO-948)	Paper No(s)/Mail Date. _____ .
3) <input type="checkbox"/> Information Disclosure Statement(s) (PTO-1449 or PTO/SB/08) Paper No(s)/Mail Date _____ .	5) <input type="checkbox"/> Notice of Informal Patent Application (PTO-152)
	6) <input type="checkbox"/> Other: _____ .

In view of the Appeal Brief filed on Jan. 26, 2004, PROSECUTION IS HEREBY REOPENED. new ground of rejection set forth below.

Claim Rejections - 35 USC § 102

The following is a quotation of the appropriate paragraphs of 35 U.S.C. § 102 that form the basis for the rejections under this section made in this Office action:

A person shall be entitled to a patent unless --

(b) the invention was patented or described in a printed publication in this or a foreign country or in public use or on sale in this country, more than one year prior to the date of application for patent in the United States.

Claims 1, 40, 42-43 are rejected under 35 U.S.C. § 102(b) as being anticipated by Takeuchi 5,907,183, newly cited.

Takeuchi discloses a method of forming a semiconductor device, which includes : forming a polysilicon conductive layer 23 or 41, figs. 2A-2B or figs. 3B+ and col. 6, lines 38+, forming a silicon nitride layer 24 (a part of NON film 27, 60 angstroms, col. 8, lines 16+), using method (10) from col. 5, lines 22-49 and col. 4, lines 8+, contacting silicon nitride layer with a mixture of hydrogen and oxidizing oxygen and nitrous gases (N₂O) to form an oxidation layer (oxide film by thermal oxidation, 25) over the silicon nitride layer 24, forming an upper polysilicon electrode 28, col. 7, lines 15+, since, capacitor is a structure of a dielectric layer sandwiched between two conductive films, hence, layers 23/24(27)/28 inherently formed a capacitor as a part of memory device, see title of invention.

Claim Rejections - 35 USC § 103

The following is a quotation of 35 U.S.C. 103(a) which forms the basis for all obviousness rejections set forth in this Office action:

(a) A patent may not be obtained though the invention is not identically disclosed or described as set forth in section 102 of this title, if the differences between the subject matter sought to be patented and the prior art are such that the subject matter as a whole would have been obvious at the time the invention was made to a person having ordinary skill in the art to which said subject matter pertains. Patentability shall not be negated by the manner in which the invention was made.

Claims 2-39, 41, 44-59 are rejected under 35 U.S.C 103 as being unpatentable over Takeuchi 5,907,183 as applied to claims 1, 40, 42-43 above, and further in view of Das et al. 6,281,141 and Lee et al. 6,015,733.

The difference between the references applied above and the instant claim(s) is: Takeuchi teaches forming an oxidation layer over a silicon nitride layer using oxidation gases but does not teach various thickness and gas flow rates. However, Das teaches at abstract and col. 8, lines 1 to col. 9, lines 42, that various coating temperature, thickness (less than 60 angstroms) and gas flow rate for forming thin oxidation oxide layer. And, Lee et al. teaches at col. 5, lines 28+, the total thickness of ONO layer is between 40 to 80 Angstroms with oxidation layer thickness at about 31 to 50 Angstroms (the nitride layer is not totally oxidized).

It would have been obvious to one of ordinary skill in the art at the time the invention was made to modify the above references' teachings with various gas flow rate and deposition temperature to obtain a desired thickness of an oxidation layer formed over a silicon nitride layer as taught by Das and Lee because an optimum capacitance of a capacitor can be obtained by simply change the thickness of the capacitor dielectric layer.

Applicant's arguments filed Jan. 26, 2004 have been fully considered but they are not persuasive. Because newly cited references teaches forming an oxidation layer over a silicon nitride layer with oxygen, hydrogen and nitrous oxide gases as set forth above.

Any inquiry of a general nature or clerical matters or relating to the status of this application or proceeding should be directed to the Group customer service whose telephone number is (571) 272-1626 and Fax number (703) 872-9306.

Any inquiry concerning this communication or earlier communications from the examiner should be directed to H. Jey Tsai whose telephone number is (571) 272-1684. The examiner can normally be reached on from 7:00 Am to 4:00 Pm., Monday thru Friday.

If attempts to reach the examiner by telephone are unsuccessful, the examiner's supervisor, John Niebling can be reached on (571) 272-1679. The fax phone number for this Group is (703) 872-9306.

hjt

4/7/04



H. Jey Tsai
Primary Examiner
Patent Examining Group 2800